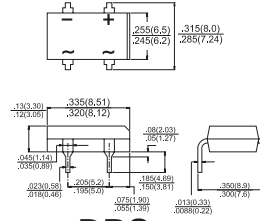


DB(S)151G - DB(S)159G

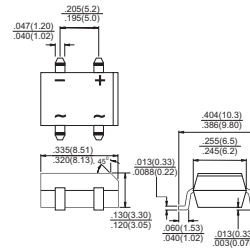
Single Phase 1.5 AMPS. Glass Passivated Bridge Rectifiers



DB



DBS



Dimensions in inches and (millimeters)

Features

- ✧ UL Recognized File # E-96005
- ✧ Glass passivated junction
- ✧ Ideal for printed circuit board
- ✧ Reliable low cost construction utilizing molded plastic technique
- ✧ High surge current capability
- ✧ High temperature soldering guaranteed: 260 °C / 10 seconds at 5 lbs., (2.3 kg) tension
- ✧ Small size, simple installation
- ✧ Pure tin plated terminal, Lead free. Leads solderable per MIL-STD-202 Method 208

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	DB 151G	DB 152G	DB 153G	DB 154G	DB 155G	DB 156G	DB 157G	DB 158G	DB 159G	Units	
		DBS 151G	DBS 152G	DBS 153G	DBS 154G	DBS 155G	DBS 156G	DBS 157G	DBS 158G	DBS 159G		
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	1200	1400	V	
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	840	980	V	
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	1200	1400	V	
Maximum Average Forward Rectified Current @ $T_A = 40^\circ C$	$I_{(AV)}$	1.5									A	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	50									A	
Rating for Fusing ($t < 8.3ms$)	I^2t	10.3									A ² sec	
Maximum Instantaneous Forward Voltage @ 1.5A	V_F	1.1						1.25			V	
Maximum DC Reverse Current @ $T_A = 25^\circ C$ at Rated DC Blocking Voltage @ $T_A = 125^\circ C$	I_R					5.0						uA uA
Typical Thermal Resistance (Note)	$R_{\theta JA}$ $R_{\theta JL}$					40 15						°C/W
Operating Temperature Range	T_J	-55 to +150									°C	
Storage Temperature Range	T_{STG}	-55 to +150									°C	

Note: Thermal resistance from Junction to Ambient and from Junction to Lead Mounted on P.C.B. with 0.4" x 0.4" (10mm x 10mm) Copper Pads.

RATINGS AND CHARACTERISTIC CURVES (DB(S)151G THRU DB(S)159G)

FIG.1- MAXIMUM DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

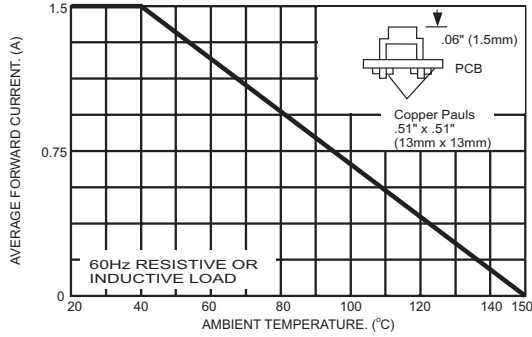


FIG.2- TYPICAL REVERSE CHARACTERISTICS PER BRIDGE ELEMENT

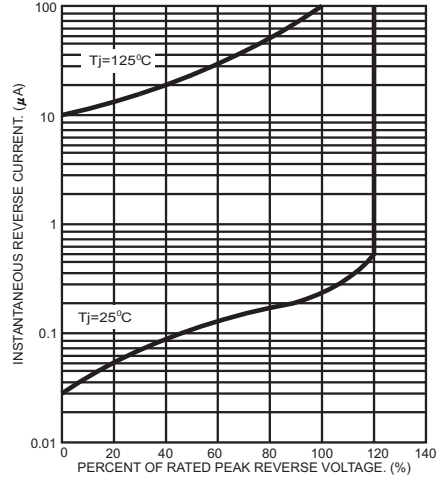


FIG.3- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT PER BRIDGE ELEMENT

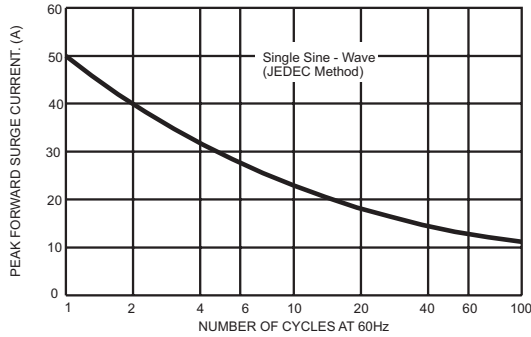


FIG.4- TYPICAL JUNCTION CAPACITANCE PER BRIDGE ELEMENT

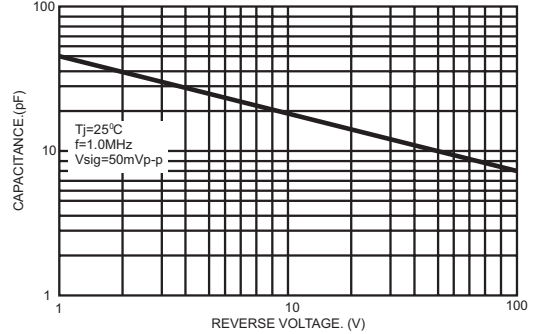
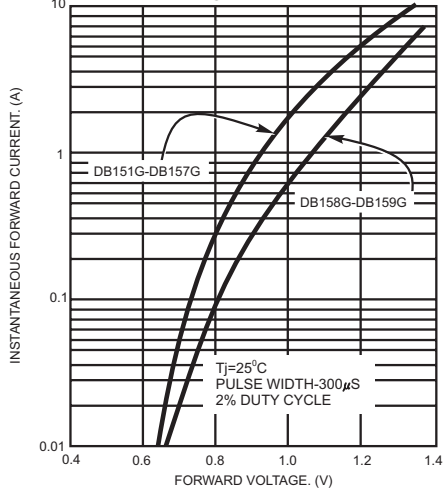


FIG.5- TYPICAL FORWARD CHARACTERISTICS PER BRIDGE ELEMENT



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[DB156G](#) [DB151G](#) [DBS151G](#)